VS-18TQ035-M3, VS-18TQ040-M3, VS-18TQ045-M3

Vishay Semiconductors

High Performance Schottky Rectifier, 18 A



www.vishay.com

2L TO-220AC

PRIMARY CHARACTERISTICS					
I _{F(AV)} 18 A					
V _R	35 V, 40 V, 45 V				
V _F at I _F	0.53 V				
I _{RM} max.	25 mA at 125 °C				
T _J max.	175 °C				
E _{AS}	24 mJ				
Package	2L TO-220AC				
Circuit configuration	Single				

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC[®]-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-18TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	18	А				
V _{RRM}	Range	35 to 45	V				
I _{FSM}	t _p = 5 μs sine	1800	А				
V _F	18 A _{pk} , T _J = 125 °C	0.53	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-18TQ035-M3	VS-18TQ040-M3	VS-18TQ045-M3	UNITS	
Maximum DC reverse voltage	V _R	35	40	45	V	
Maximum working peak reverse voltage	V _{RWM}		40	45	v	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current, see fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 149 °C	18				
Maximum peak one cycle	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	1800	A		
non-repetitive surge current, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	390			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3.6 A, L = 3.7 mH		24	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		3.6	А		

Revision: 23-Nov-17 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000





www.vishay.com

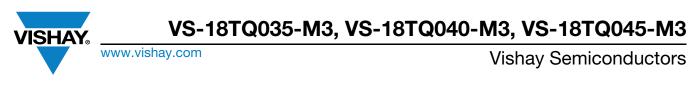
Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		18 A	T _{.1} = 25 °C	0.60			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	36 A	1j=25 C	0.72	V		
See fig. 1	VFM ()	18 A	T _{.1} = 125 °C	0.53			
		36 A	1j = 125 0	0.67			
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2.5	mA		
See fig. 2	IRM ("	T _J = 125 °C	$v_{\rm R} = haleu v_{\rm R}$	25	IIIA		
Maximum junction capacitance	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		1400	pF		
Typical series inductance	L _S	Measured lead to lead 5 m	8	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and st temperature range	orage	T _J , T _{Stg}		-55 to +175	°C		
Maximum thermal resista junction to case	nce,	R _{thJC}	DC operation See fig. 4	1.50	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50			
Approximate weight				2	g		
				0.07	OZ.		
Mounting torque	minimum			6 (5)	kgf ⋅ cm		
Mounting torque	maximum			12 (10)	(lbf ⟨ in)		
				18TC	Q035		
Marking device			Case style 2L TO-220AC	18TC	Q040		
				18TC	2045		



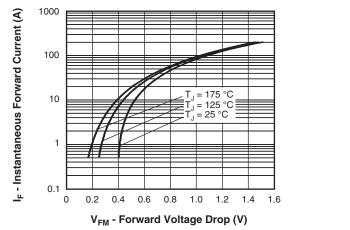


Fig. 1 - Maximum Forward Voltage Drop Characteristics

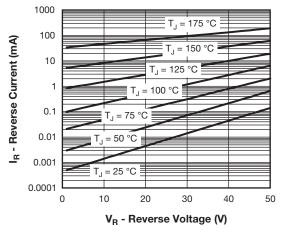


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

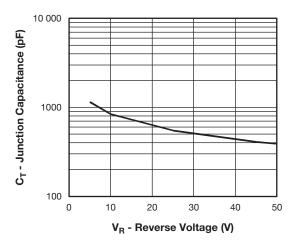


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

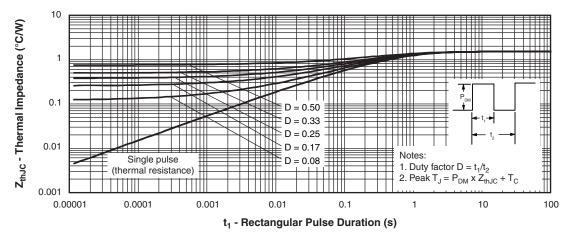
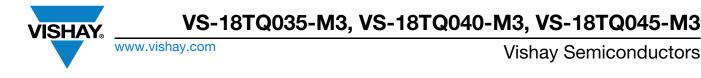
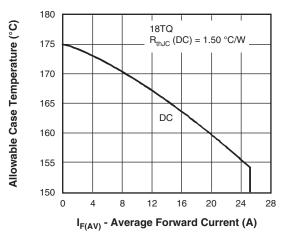


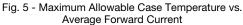
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

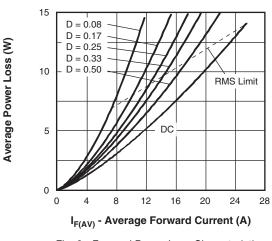
 Revision: 23-Nov-17
 3
 Document Number: 96262

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000











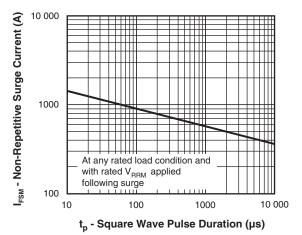


Fig. 7 - Maximum Non-Repetitive Surge Current

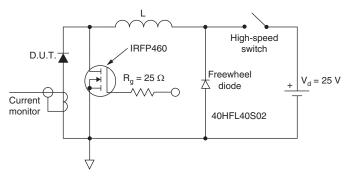


Fig. 8 - Unclamped Inductive Test Circuit

VS-18TQ035-M3, VS-18TQ040-M3, VS-18TQ045-M3



www.vishay.com

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device

code	VS-	18	т	Q	045	-M3	
		2	(3)	(4)	(5)	6	
	2	- Cur	rent rati		ctors pro	oduct	
	3 · 4 ·	T =	kage: TO-220 ottky "Q				035 = 35 V
		- Volt	age rati ironmer	ngs —			040 = 40 V 045 = 45 V
		-M3	= halog	jen-free	, RoHS-	complia	nt, and termination lead (Pb)-fre

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-18TQ035-M3	50	1000	Antistatic plastic tube				
VS-18TQ040-M3	50	1000	Antistatic plastic tube				
VS-18TQ045-M3	50	1000	Antistatic plastic tube				

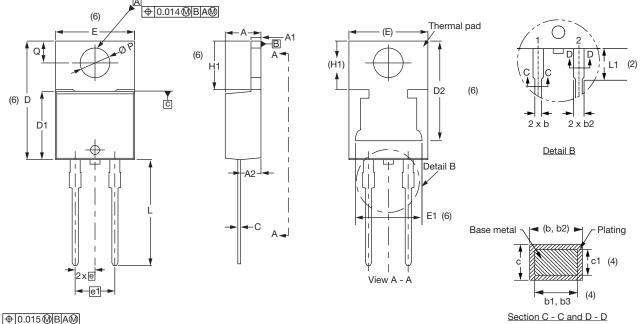
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96156			
Part marking information	www.vishay.com/doc?95391			
SPICE model	www.vishay.com/doc?96209			

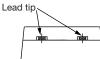


Vishay Semiconductors

2L TO-220AC

DIMENSIONS in millimeters and inches





SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC®	outline	TO-220AC
--------------------	---------	----------

SYMBOL	MBOI MILLIMETERS INCHES		NOTES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 13-Jun-2019

1

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.